

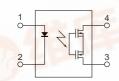


GU (General Use) Type SOP Series 1- Channel (Form B) 4-Pin Type

PhotoMOS RELAYS



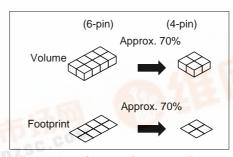
mm inch



FEATURES

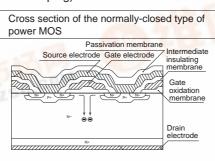
1. SO package 4-Pin type in super miniature design

The device comes in a super-miniature SO package 4-Pin type measuring (W) 4.3×(L) 4.4×(H) 2.1 mm (W) .169×(L) .173×(H) .083 inch —approx. 70% of the volume and 70% of the footprint size of SO package 6-pin type PhotoMOS Relays.



2. Low on resistance for normallyclosed type

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



3. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

4. Controls low-level analog signalsPhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without dis-

5. Low-level off state leakage current In contrast to the SSR with an off state leakage current of several milliamps, the PhotoMOS relay features a very small off state leakage current of 1nA even with the rated load voltage of 350 V (AQY410S).

TYPICAL APPLICATIONS

- Telecommunications (PC, Electoronic Notepad)
- Measuring and Testing equipment
- Factory Automation Equipment
- Security equipment
- High speed inspection machines

WWW.DZSG

TYPES

AC/DC type

Output rating*		Par	Packing quantity in tape		
Load voltage	Load current	Picked from the 1/2-pin side	Picked from the 3/4-pin side	and reel	
350 V	120 mA	AQY410SX	AQY410SZ	1 000 pee	
400 V	100 mA	AQY414SX	AQY414SZ	1,000 pcs.	

^{*} Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 100 pcs.; Case: 2,000 pcs.)

(2) For space reasons, the top two letters of the product number "AQY" and "S" are omitted on the product seal. The package type indicator "X" and "Z" are omitted from the seal. (Ex. the label for product number AQY414S is 414).

RATING

AC/DC type

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY410S	AQY414S	Remarks
	LED forward current	IF I	50 mA		
Input	LED reverse voltage	VR	3 V		
	Peak forward current	IFP	1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW		
Output	Load voltage (peak AC)	VL	350 V	400 V	
	Continuous load current (peak AC)	lL	0.12 A	0.1 A	
	Peak load current	Ipeak	0.3 A	0.24 A	100ms (1 shot), V _L = DC
	Power dissipation	Pout	300 mW		
Total power dissipation		P⊤	350 mW		
I/O isolation voltage		Viso	1,500 V AC		
Temperture	mperture Operating		-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures
fimits #	Storage	Tsta	-40°C to +100°C -40°F to +212°F		

AQY41OS

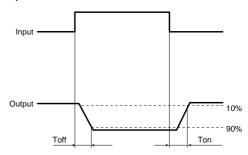
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY410S	AQY414S	Remarks	
Input	LED operate (OFF) current	Typical	I Fon	0.9 mA		IL = Max.
		Maximum		3 mA		
	LED reverse (ON) current	Minimum	I Foff	0.4 mA		IL = Max.
		Typical		0.85 mA		
	LED dropout voltage	Typical	VF	1.14 V (1.25 V at I _F = 50 mA)		IF = 5 mA
		Maximum	VF	1.5 V		
Output	On resistance	Typical	Ron	18 Ω	26 Ω	IF = 0 mA IL = Max.
		Maximum		25 Ω	35 Ω	Within 1 s on time
	Off state leak- age current	Maximum	Leak	1 μΑ		I _F = 5 mA V _L = Max.
Transfer characteristics	Operate (OFF) time*	Typical	Ton	0.52 ms	0.47 ms	I _F = 0 mA>5 mA
		Maximum	I on	1 ms		I∟ = Max.
	Reverse (ON) time*	Typical	Toff	0.23 ms	0.28 ms	I _F = 5 mA>0 mA
		Maximum		1 ms		I∟ = Max.
	I/O capacitance	Typical	Ciso	0.8 pF		f = 1 MHz V _B = 0
		Maximum	Oiso	1.5 pF		
	Initial I/O isolation resistance	Minimum	Riso	1,000 ΜΩ		500 V DC

Note: Recommendable LED forward current IF = 5mA.

For type of connection, see page 32.

*Operate/Reverse time



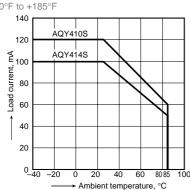
- **■** For Dimensions, see Page 28.
- For Schematic and Wiring Diagrams, see Page 32.
- For Cautions for Use, see Page 36.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

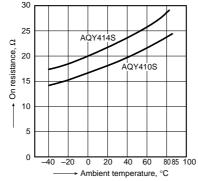
Allowable ambient temperature: –40°C to +85°C

-40°F to +185°F

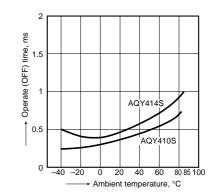


2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 0 mA; Continuous load current: Max.(DC)

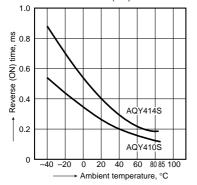


- 3. Operate (OFF) time vs. ambient temperature characteristics
- LED current: 5 mA; Load voltage: Max.(DC); Continuous load current: Max.(DC)



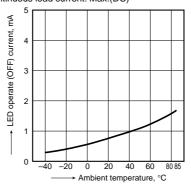
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max.(DC); Continuous load current: Max.(DC)



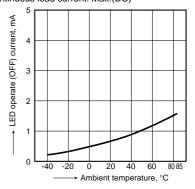
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max.(DC); Continuous load current: Max.(DC)



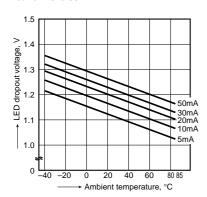
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max.(DC); Continuous load current: Max.(DC)



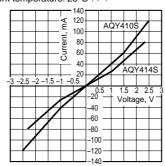
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



8. Voltage vs. current characteristics of output at MOS portion

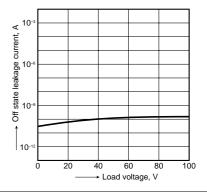
Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



9. Off state leakage current

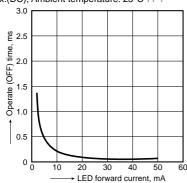
Measured portion: between terminals 3 and 4; LED current: 5 mA;

Ambient temperature: 25°C 77°F



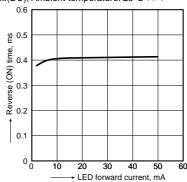
10. LED forward current vs. operate (OFF) time characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max.(DC); Continuous load current: Max.(DC); Ambient temperature: 25°C 77°F



11. LED forward current vs. reverse (ON) time characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max.(DC); Continuous load current-Max.(DC); Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz;

Ambient temperature: 25°C 77°F

